## NSN 5961-00-947-5733

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**Inclosure Material:** 

Metal

**Overall Length:** 

0.800 inches

#### **Overall Height:**

0.406 inches

#### **Overall Diameter:**

0.424 inches

#### **Mounting Facility Quantity:**

1

#### Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

#### Features Provided:

Hermetically sealed case

#### **Overall Width Across Flats:**

0.564 inches

#### Thread Size:

0.190 inches

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-emitter, with specified circuit between base and emitter and 20.0 base to emitter voltage, dc

#### **Current Rating Per Characteristic:**

20.00 milliamperes source cutoff current

#### Power Rating Per Characteristic:

200.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Thread Series Designator:**

Unf

## Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

#### Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

